

Technical Data Data Sheet 688, Rev.-

SILICON SCHOTTKY RECTIFIER DIE Very Low Forward Voltage Drop (150 °C T_J Operation)

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Electrically / Mechanically Stable during and after Packaging

Maximum Ratings⁽¹⁾:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V_{RWM}	-	60	V
Max. Average Forward Current	$I_{F(AV)}$	50% duty cycle, rectangular wave form	60	А
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave	860	А
Non-Repetitive Avalanche Energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 8.0 \text{A}, \\ L = 1.7 \text{mH}$	54	mJ
Repetitive Avalanche Current	I _{AR}	I_{AS} decay linearly to 0 in 1 μs f limited by T_J max V_A =1.5 V_R	8.0	А
Max. Junction Temperature	T_J	-	-65 to +150	°C
Max. Storage Temperature	T_{stg}	-	-65 to +150	°C

Electrical Characteristics(1):

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 60A, Pulse, T _J = 25 °C	0.60	V
	V_{F2}	@ 60A, Pulse, T _J = 125 °C	0.57	V
Max. Reverse Current	I _{R1}	@V _R = 60V, Pulse,	6.0	mA
		$T_J = 25 ^{\circ}C$		
	I_{R2}	$@V_R = 60V$, Pulse,	420	mA
		T _J = 125 °C		
Max. Junction Capacitance	C _T	$@V_R = 5V, T_C = 25 ^{\circ}C$	2400	pF
		$f_{SIG} = 1MHz,$		
		$V_{SIG} = 50 \text{mV} (p-p)$		

(1) in SHD package

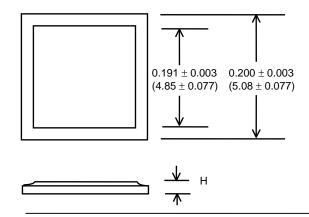
^{• 221} West Industry Court ☐ Deer Park, NY 11729-4681 ☐ (631) 586-7600 FAX (631) 242-9798 •

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SENSITRON SEMICONDUCTOR

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Mechanical Dimensions: In Inches / mm



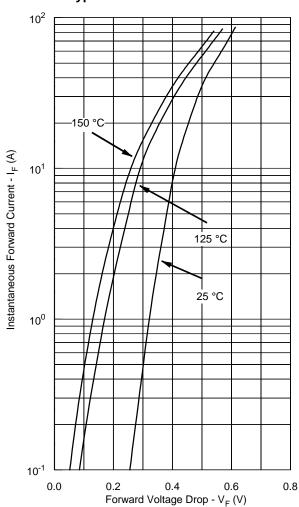
Bottom side metalization Ag - 30 kÅ minimum.

Top side metalization AI - 25 kÅ minimum or Ag - 30 kÅ minimum.

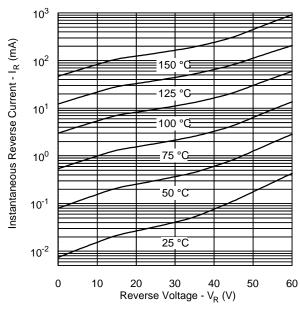
Bottom side is cathode, top side is anode.

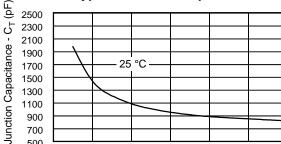
Dimension H = $0.0105 \pm 0.001 (0.27 \pm 0.026)$ for AI top; Dimension H = 0.0155 \pm 0.001 (0.39 \pm 0.026) for Ag top.

Typical Forward Characteristics

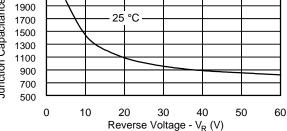


Typical Reverse Characteristics





Typical Junction Capacitance



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